IAPPLICATION Biaxially-textured film deposition for superconductor coated tapes US Pat. 10821010 - Filed Apr 8, 2004 In this invention, the ion beam incident angle is arranged so that it is along the BITD while, at the same time, the deposition flux incident plane is ...

Thin films having rock-salt-like structure deposited on amorphous surfaces US Pat. 6190752 - Filed Nov 12, 1998 - Board of Trustees of the Leland Stanford Junior University In one example MgO IBAD films 16 were deposited on an amorphous Si3N4 layer ... The flux ranged from 110-120 //A/cm2. The angle between the ion beam and the ...

Method for preparing high temperature superconductor US Pat. 6361598 - Filed Jul 20, 2000 - The University of Chicago Typical IBAD deposition rates are about 1.5 A/seconds. ... technique can be used to create a plume of incident flux which travels toward a substrate. ...

Superconductor fabrication processes US Pat. 7338683 - Filed May 10, 2004 - Superpower, Inc. According to an embodiment, the IBAD (ion beam assisted deposition) system ... the buffer layer during deposition at a oblique 55 incident angle from ...

Methods for forming superconducting conductors US Pat. 6998028 - Filed Sep 24, 2004 - Superpower, Inc. According to an embodiment, ion beam assisted deposition is utilized to ... and the growing buffer film) during deposition, at a oblique incident angle from ...